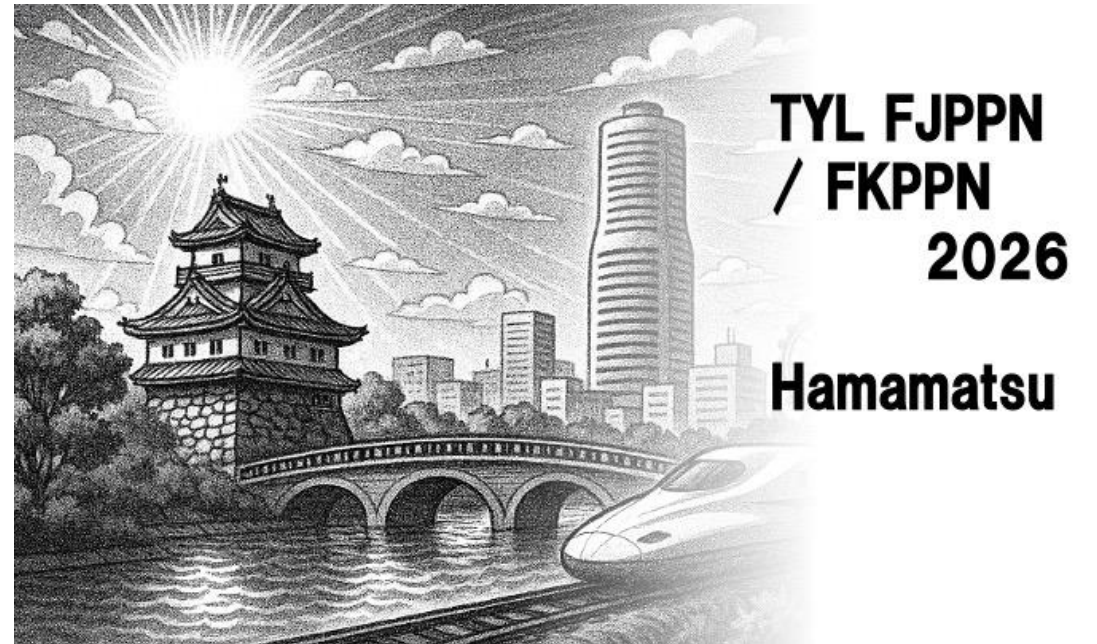


# A\_RD\_25: Continued Effort Towards Ultimate Performance for Accelerator Cavities



# Overview of the project

<b>A_RD_25</b>	<b>Title: A_RD_25 Continued effort towards ultimate performance for accelerator cavities</b>					
<b>PIs:</b>  <b>Members:</b>	<b>French Group</b>			<b>Japanese Group</b>		
	<b>name</b> (Family name, First name)	<b>title</b>	<b>lab.<sup>1</sup></b>	<b>name</b> (Family name, First name)	<b>title</b>	<b>lab.<sup>22</sup></b>
	Yasmine KALBOUSSI	Dr.	IRFU/CEA	Takayuki KUBO	Dr.	KEK
	Thomas PROSLIER	Dr.	IRFU/CEA	Takayuki SAEKI	Dr.	KEK
	Grégoire JULLIEN	Mr.	IRFU/CEA	Ryo KATAYAMA	Dr.	KEK
	Enrico CENNI	Dr.	IRFU/CEA	Takeyoshi GOTO	Dr.	KEK
	Fabien EOZENOU	Mr.	IRFU/CEA	Yasuhiro FUWA	Dr.	JAEA
				Yoshihisa IWASHITA	Dr.	U. Osaka RCNP

In order to establish the scientific basis for high-performance SRF (Superconducting Radio Frequency) cavities, this project pursues a unified approach that combines cavity fabrication, surface-treatment development (such as EP: Electro-Polishing), thin film deposition technique, and theoretical understanding.

# **Continued Effort Towards Ultimate Performance for Accelerator Cavities**

## **Activities in 2025 and Plan for 2026**

- |    |  |                           |
|----|--|---------------------------|
| 1. | Theoretical Analysis                   | T. Kubo                   |
| 2. | Nb <sub>3</sub> Sn Thin Film Formation | R. Katayama               |
| 3. | 3GHz cavity                            | Y. Fuwa                   |
| 4. | EP with organic solvent                | T. Goto                   |
| 5. | EP with depleted HF mixture            | F. Eozenou                |
| 6. | Atomic Layer Deposition                | Y. Kalboussi & T. Proslie |
| 7. | Faint Magnetic Shielding               | Y. Iwashita               |

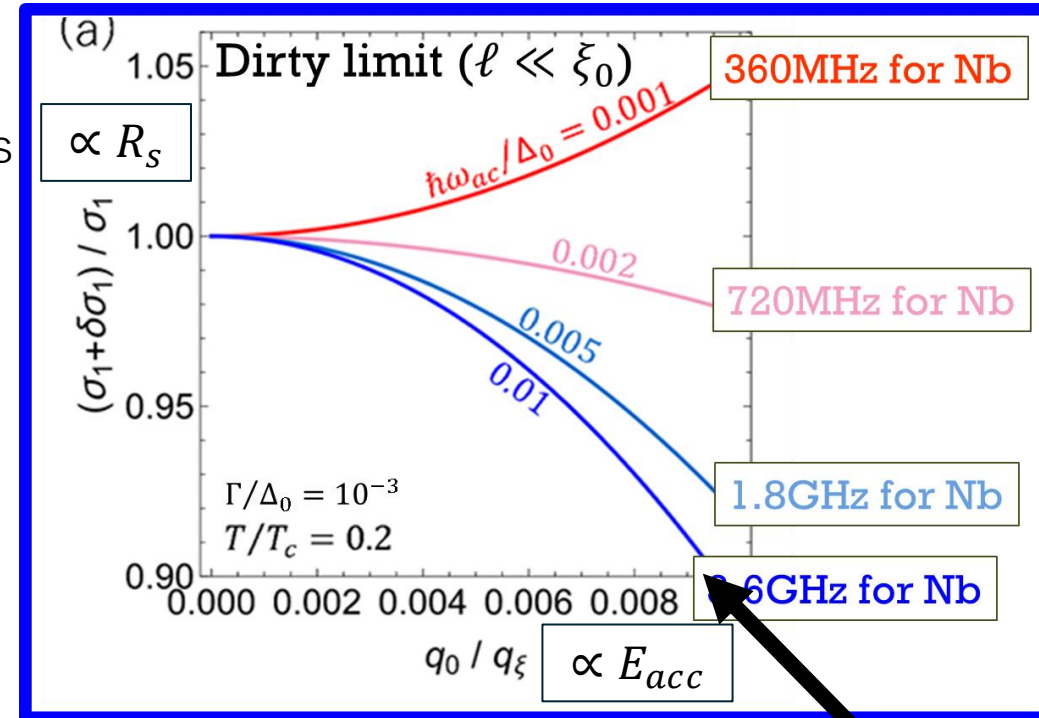
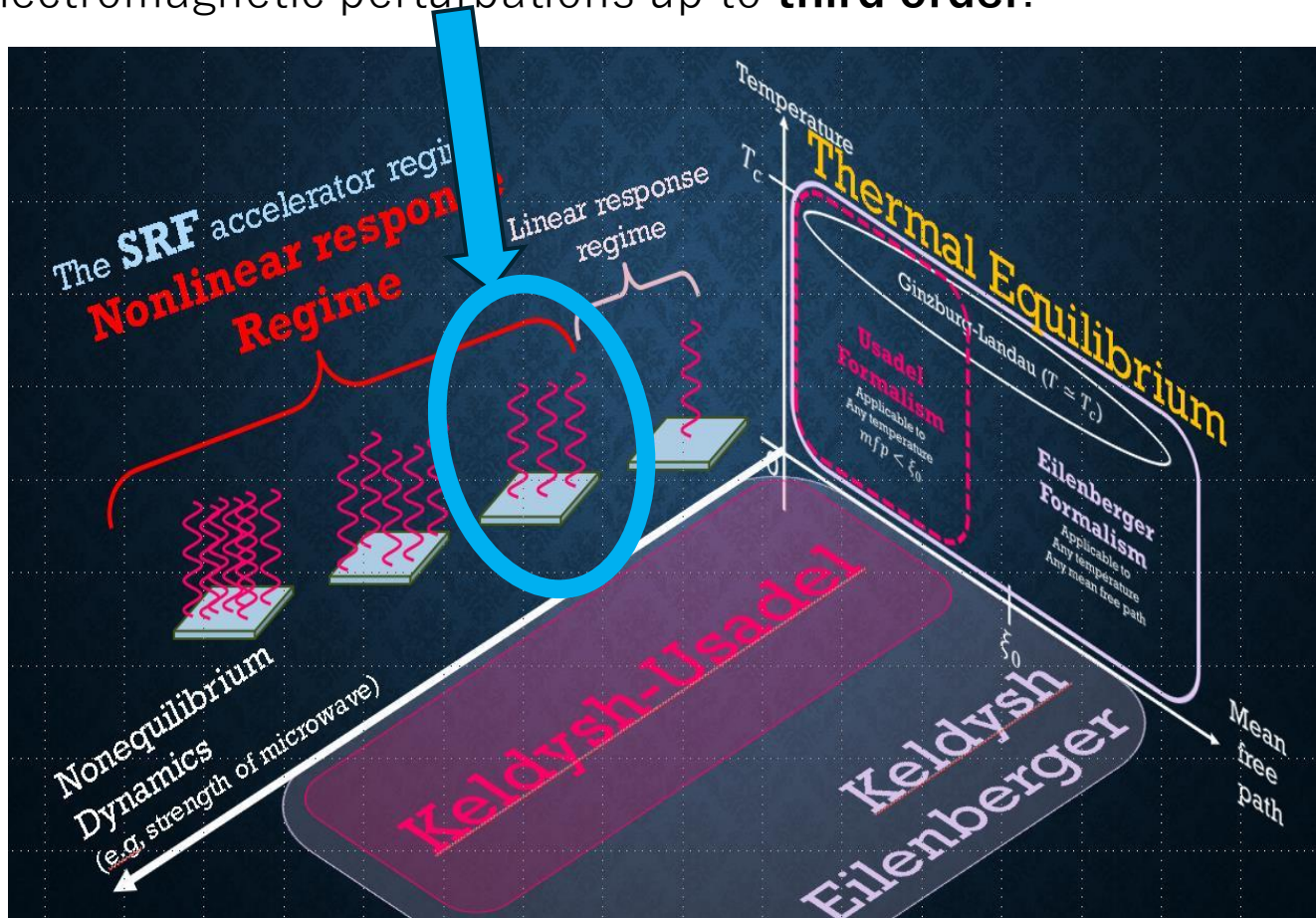
# **Continued Effort Towards Ultimate Performance for Accelerator Cavities**

## **Activities in 2025 and Plan for 2026**

- |  |                                      |
|--|--------------------------------------|
| <b>1. Theoretical Analysis</b>                 | <b>T. Kubo</b>                       |
| <b>2. Nb<sub>3</sub>Sn Thin Film Formation</b> | <b>R. Katayama</b>                   |
| <b>3. 3GHz cavity</b>                          | <b>Y. Fuwa</b>                       |
| <b>4. EP with organic solvent</b>              | <b>T. Goto</b>                       |
| <b>5. EP with depleted HF mixture</b>          | <b>F. Eozenou</b>                    |
| <b>6. Atomic Layer Deposition</b>              | <b>Y. Kalboussi &amp; T. Proslie</b> |
| <b>7. Faint Magnetic Shielding</b>             | <b>Y. Iwashita</b>                   |

# Achievement in 2025: Amplitude-dependent Electromagnetic response

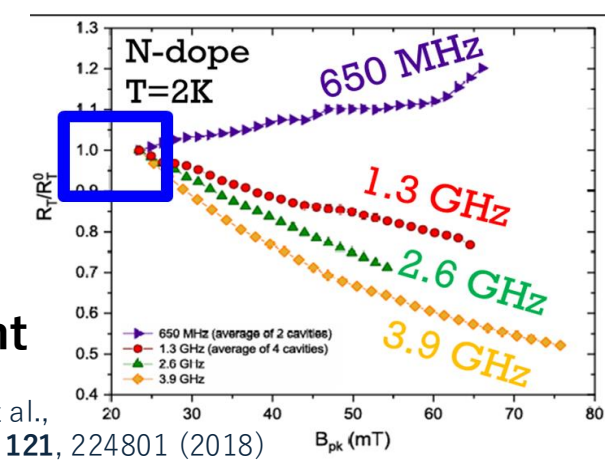
The nonlinear behavior routinely observed in SRF  $Q$ - $E$  curves is a **problem of nonequilibrium superconductivity under extremely strong rf electromagnetic fields**. Linear-response theories such as Mattis-Bardeen are no longer sufficient. Kubo addressed this long-standing problem using the Keldysh-Usadel theory, **a microscopic theory of nonequilibrium superconductivity**, by including electromagnetic perturbations up to **third order**.



Theory T. Kubo, Phys. Rev. Applied **24**, 064061 (2026)  
 Note: this corresponds to a few (mT)

Anti  $R_{BCS}$  slope at  $f \gtrsim 1$  GHz

Experiment



M. Martinello et al., Phys. Rev. Lett. **121**, 224801 (2018)

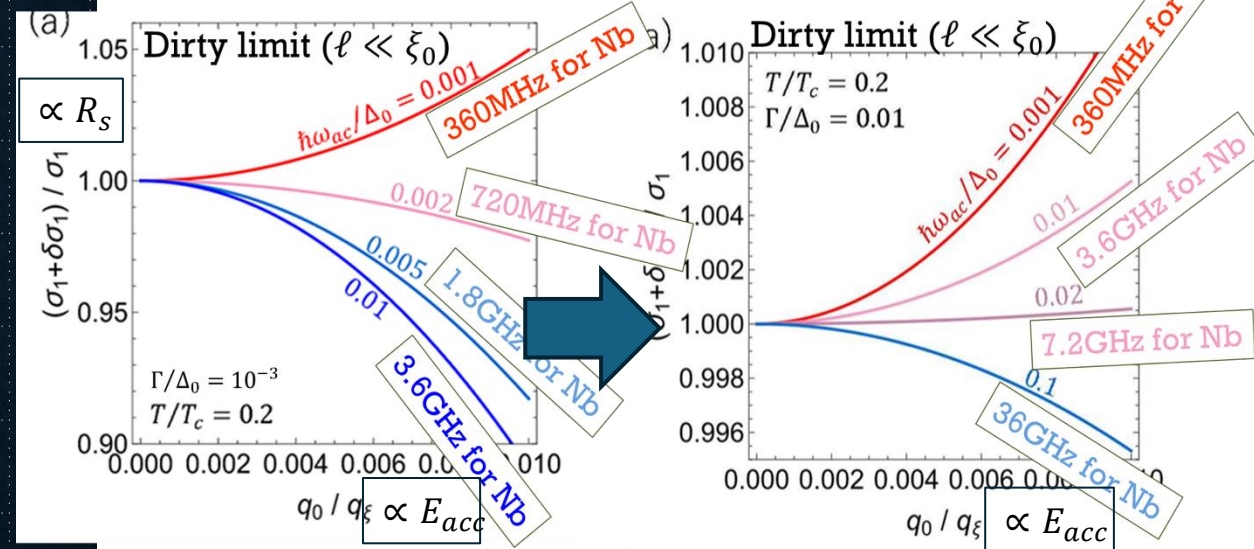
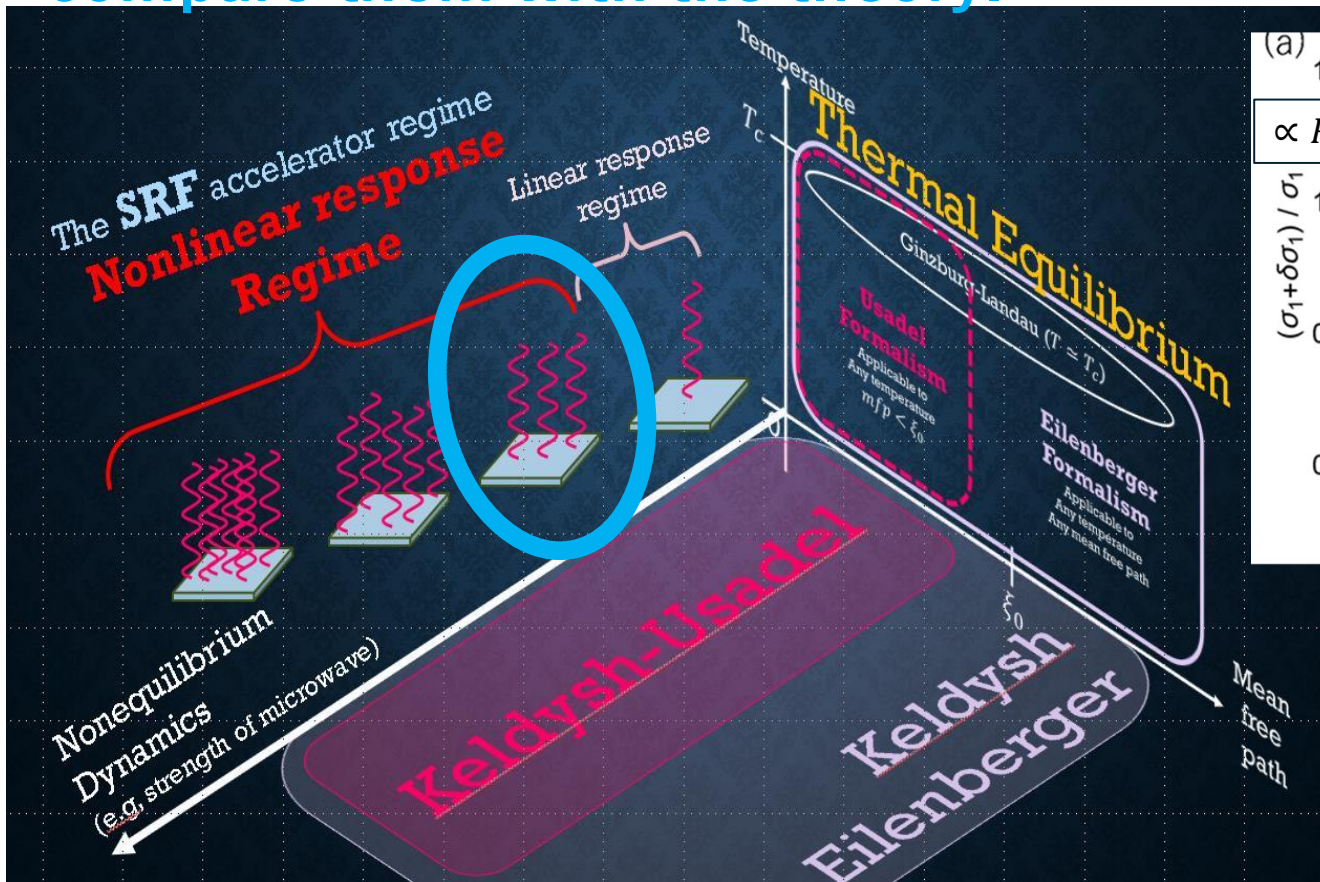
# Theoretical prediction and the 2026 target

- Even when  $\Gamma$  is not as small as in N-doped cavities, the anti-  $R_{BCS}$  behavior can become visible by increasing the frequency.
- We will revisit existing Q-E measurements and tunneling-spectroscopy data, and compare them with the theory.

The inelastic scattering rate affects the “switching frequency” of  $R_{BCS}$  slope

$$\Gamma/\Delta_0 = 0.001 \quad \Rightarrow \quad \Gamma/\Delta_0 = 0.01$$

(e.g., nitrogen dope)



Anti  $R_{BCS}$  slope at  $f \gtrsim 1$  GHz  $\Rightarrow$  Anti  $R_{BCS}$  slope at  $f \gtrsim 10$  GHz

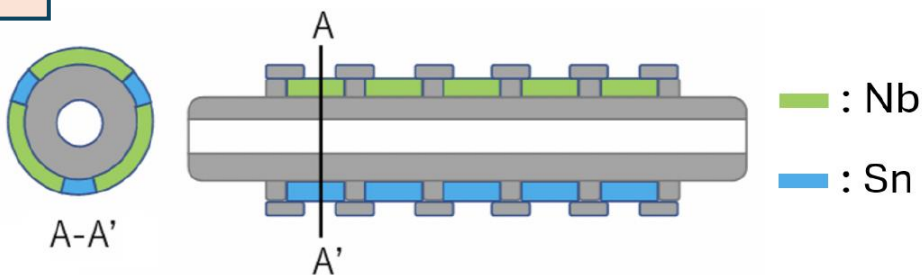
# **Continued Effort Towards Ultimate Performance for Accelerator Cavities**

## **Activities in 2025 and Plan for 2026**

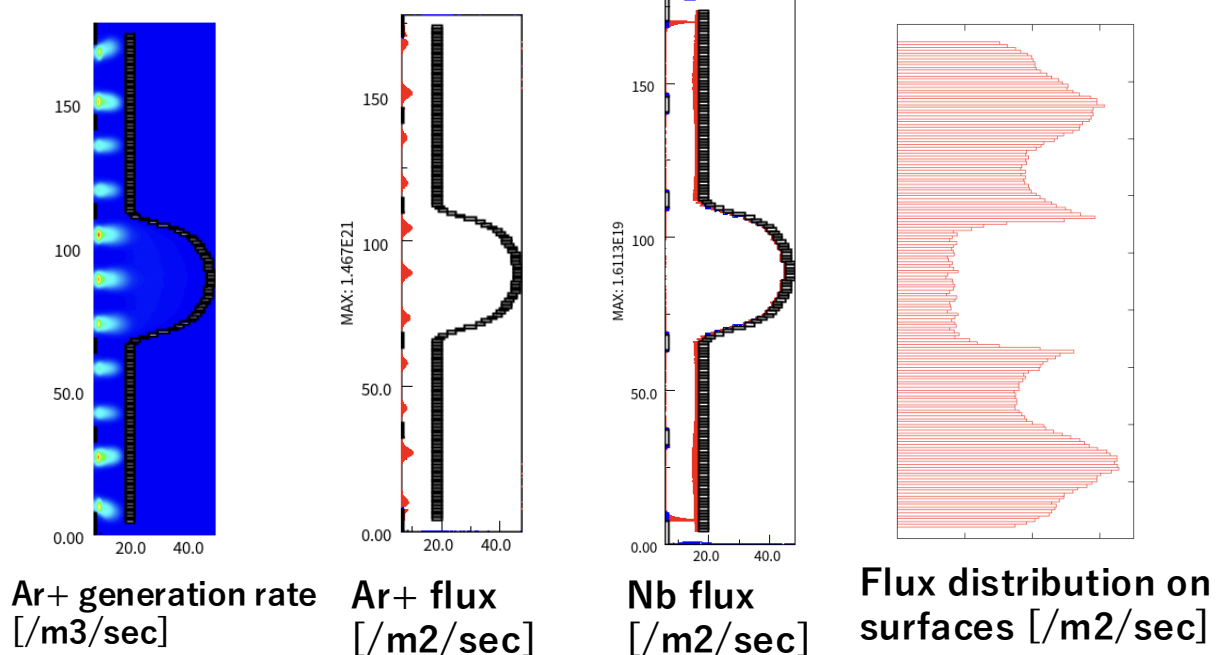
- |    |   |                           |
|----|---|---------------------------|
| 1. | Theoretical Analysis                        | T. Kubo                   |
| 2. | <b>Nb<sub>3</sub>Sn Thin Film Formation</b> | <b>R. Katayama</b>        |
| 3. | 3GHz cavity                                 | Y. Fuwa                   |
| 4. | EP with organic solvent                     | T. Goto                   |
| 5. | EP with depleted HF mixture                 | F. Eozenou                |
| 6. | Atomic Layer Deposition                     | Y. Kalboussi & T. Proslie |
| 7. | Faint Magnetic Shielding                    | Y. Iwashita               |

# Simulation Study for Nb<sub>3</sub>Sn Film Formation Assuming DC-Magnetron Sputtering

T.Sasaki

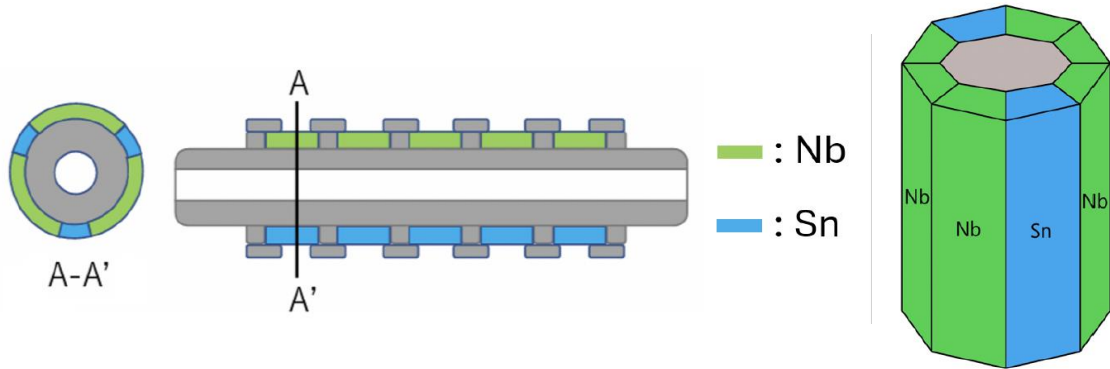


Design concept of a special Nb-Sn mixed cathode for Nb<sub>3</sub>Sn film-formation by high-temperature annealing



- Sputtering simulations were performed to investigate the film-formation conditions required to achieve an Nb:Sn mixing ratio of 3:1 for Nb<sub>3</sub>Sn coating inside a 3 GHz cavity by DC magnetron sputtering.
- We performed the simulations using software modules provided by PEGASAS Software Inc.
- Nb and Sn flux distributions emitted from pure Nb and Sn cathodes were evaluated on the cavity inner surface.
- Based on the obtained results, a candidate design for an Nb-Sn mixed cathode was proposed to achieve the desired Nb<sub>3</sub>Sn precursor layer.

# Sputtering Test Using a Prototype Bi-Metal Mixed Cathode



- We fabricated a special cathode base that we can cover with two metals, as shown in the left figure.
- This structure corresponds to a prototype Nb-Sn mixed cathode for creating Nb<sub>3</sub>Sn precursor layer.
- We assembled a SUS-AI mixed cathode and performed a film-formation test in the KEK sputtering apparatus.
- As a result, formation of an SUS-AI mixed film on a silicon wafer was confirmed, as shown in the lower-left figure.

# Plan for 2026

- We will complete the development of an Nb-Sn mixed cathode capable of producing an Nb:Sn = 3:1 precursor layer and fabricate Nb<sub>3</sub>Sn films on the inner surface of our 3 GHz cavity.
- Further sputtering simulations and detailed surface analyses will be conducted to optimize the deposition and annealing conditions for Nb<sub>3</sub>Sn synthesis.

# Continued Effort Towards Ultimate Performance for Accelerator Cavities

## Activities in 2025 and Plan for 2026

- |    |  |                           |
|----|--|---------------------------|
| 1. | Theoretical Analysis                   | T. Kubo                   |
| 2. | Nb <sub>3</sub> Sn Thin Film Formation | R. Katayama               |
| 3. | <b>3GHz cavity</b>                     | <b>Y. Fuwa</b>            |
| 4. | EP with organic solvent                | T. Goto                   |
| 5. | EP with depleted HF mixture            | F. Eozenou                |
| 6. | Atomic Layer Deposition                | Y. Kalboussi & T. Proslie |
| 7. | Faint Magnetic Shielding               | Y. Iwashita               |

# [2025] Vertical Test of a 3GHz cavity

Vertical test (VT) was performed to measure the RF performance of a (bare) 3 GHz cavity at KEK-STF.

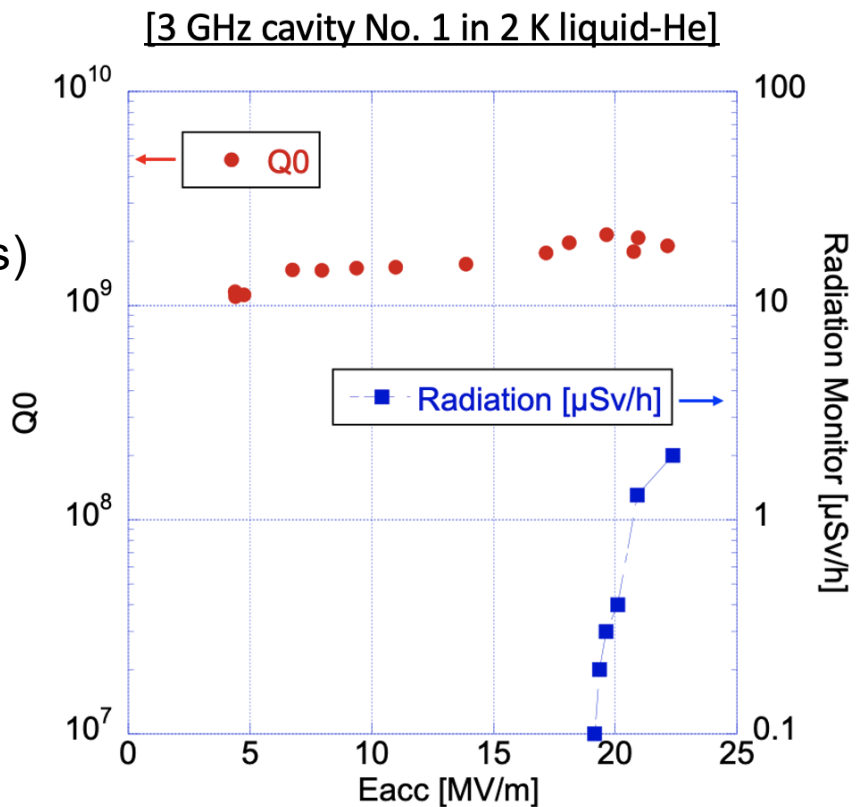


### Surface Treatment Process

- BCP (30  $\mu\text{m}$ )
- EP1 (100  $\mu\text{m}$ ,  $< 50^\circ\text{C}$ )
- Annealing (900  $^\circ\text{C}$ , 3h)
- (Mechanical polishing to remove defects)
- EP2 (30 $\mu\text{m}$ ,  $< 20^\circ\text{C}$ )
- High-Pressure Rinse
- Assembly in Clean Room
- Baking (120 $^\circ\text{C}$ , 48h)

### Result

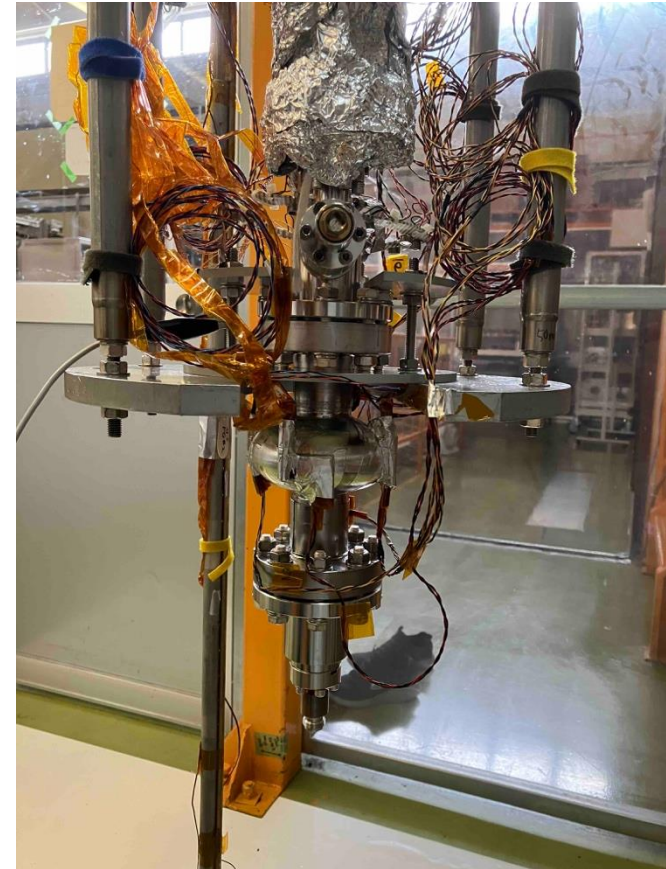
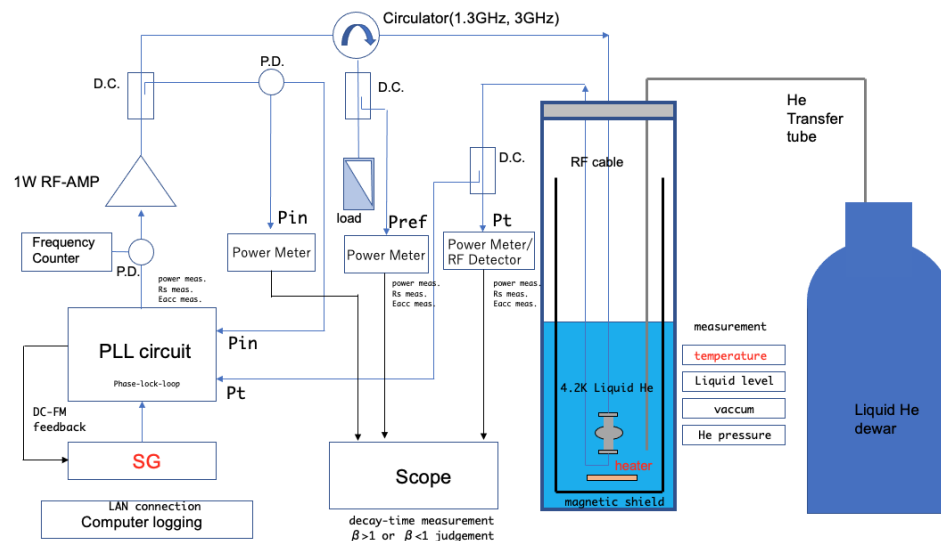
- $E_{\text{acc}} \sim 22 \text{ MV/m}$
- $Q_0 \sim 2 \times 10^9$  (@ 2K)



# [2026 plan] 3GHz cavity

To efficiently conduct tests on cavities coated with thin films, we will establish the necessary infrastructure for 3 GHz cavity testing, such as,

- RF control system
- Data acquisition system
- Data analysis system
- ...



# Continued Effort Towards Ultimate Performance for Accelerator Cavities

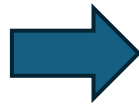
## Activities in 2025 and Plan for 2026

- |    |  |                           |
|----|--|---------------------------|
| 1. | Theoretical Analysis                   | T. Kubo                   |
| 2. | Nb <sub>3</sub> Sn Thin Film Formation | R. Katayama               |
| 3. | 3GHz cavity                            | Y. Fuwa                   |
| 4. | EP with organic solvent                | T. Goto                   |
| 5. | EP with depleted HF mixture            | F. Eozenou                |
| 6. | Atomic Layer Deposition                | Y. Kalboussi & T. Proslie |
| 7. | Faint Magnetic Shielding               | Y. Iwashita               |

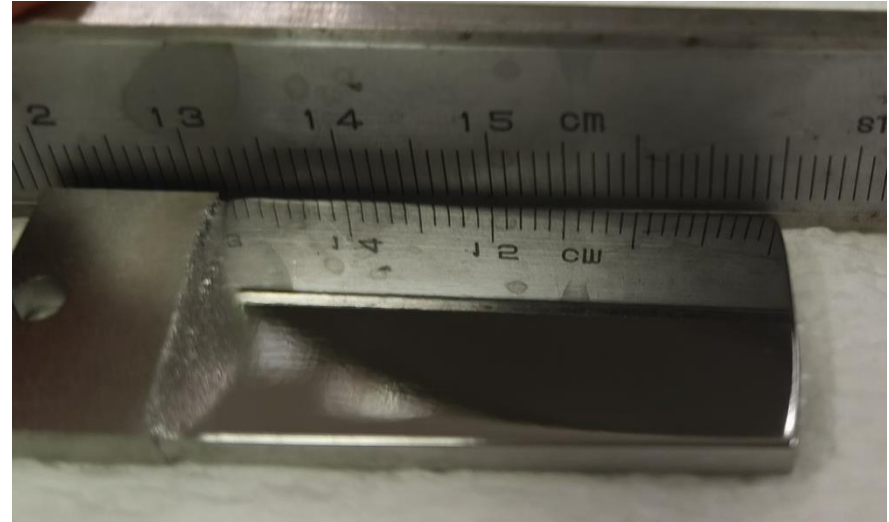
## Development of organic solvent EP for higher gradient Nb cavity

- 1) very safe to handle the electrolyte solution
- 2) higher gradient performance by generating much more pristine Nb surface
  - Hydrogen storage in the Vacancy and defect is much reduced.
  - Vacancy formation during EP reaction becomes much less.
  - Skipping 120 °C 48 hr baking of Nb cavity results in no oxygen diffusion on the surface.

sanding and CP



organic solvent EP

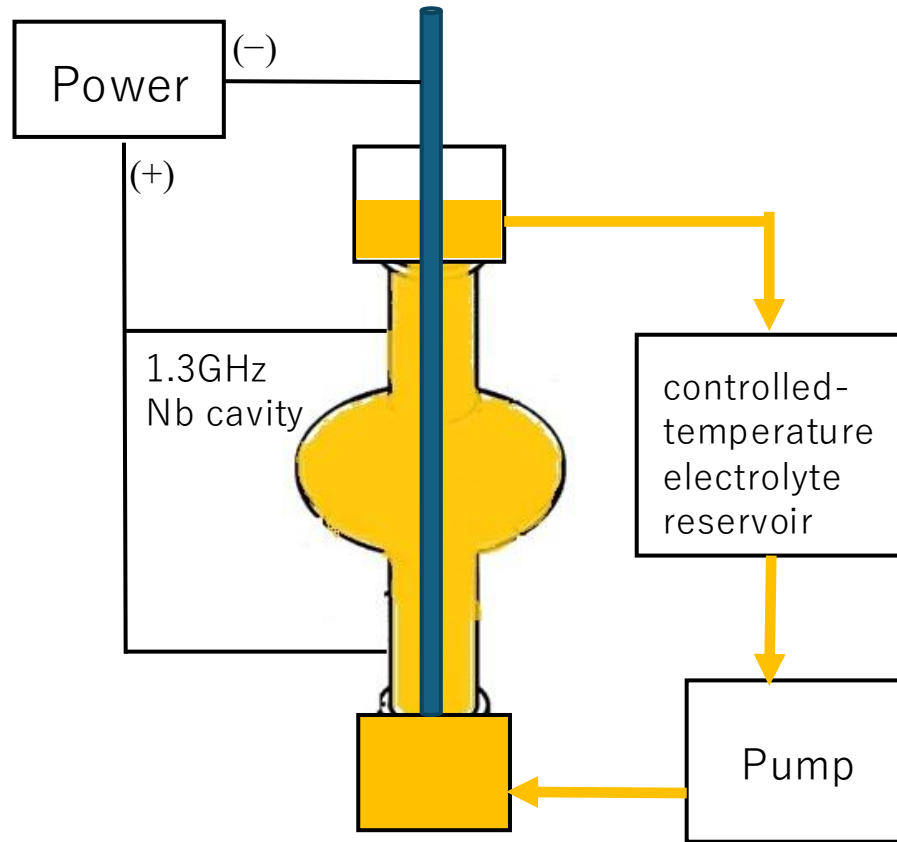


electrolyte: confidential due to patent application  
conditions: 16 cm<sup>2</sup> (both sides), 20 °C, 24 V 180 min,  
~50 mAcm<sup>-2</sup>, 36 μm/hr, total ~100 μm polished.

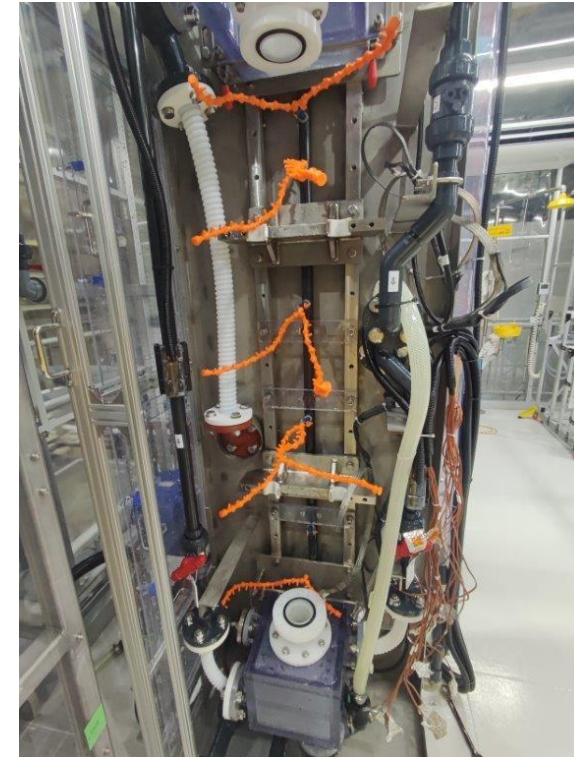
Both sides of the Nb substrate have a perfectly mirror-like finish!!

## Plan for 2026: scale up to 1.3 GHz 1 cell cavity

cathode rod



cavity stand at COI



- For a larger sample area, the experimental conditions will be more optimized for single cell cavity. (surface area:  $\sim 1000 \text{ cm}^2$ )

Difficulties:

- >> The cathode has a smaller surface area than the anode (cavity).
- >> The distance between the cathode and the anode varies depending on the location of the cavity.

# Continued Effort Towards Ultimate Performance for Accelerator Cavities

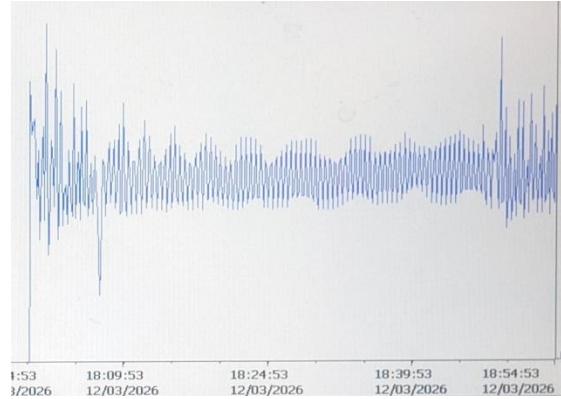
## Activities in 2025 and Plan for 2026

- |    |  |                           |
|----|--|---------------------------|
| 1. | Theoretical Analysis                   | T. Kubo                   |
| 2. | Nb <sub>3</sub> Sn Thin Film Formation | R. Katayama               |
| 3. | 3GHz cavity                            | Y. Fuwa                   |
| 4. | EP with organic solvent                | T. Goto                   |
| 5. | EP with depleted HF mixture            | F. Eozenou                |
| 6. | Atomic Layer Deposition                | Y. Kalboussi & T. Proslie |
| 7. | Faint Magnetic Shielding               | Y. Iwashita               |

# EP WITH DEPLETED HF MIXTURE CAVITY EXPERIMENT (1Cell 1.3 GHz)



RI02 after bulk VEP

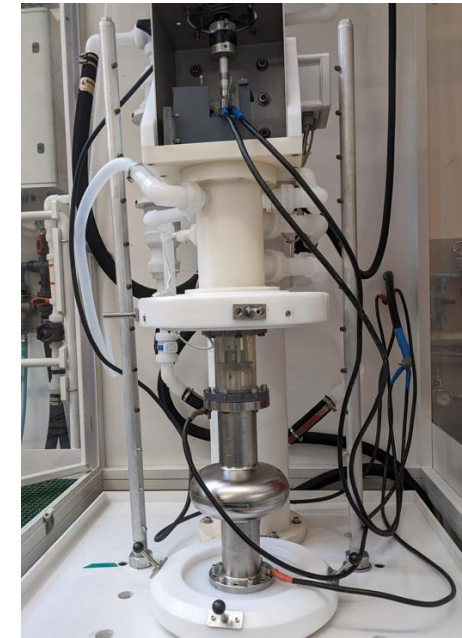


Current oscillations during treatment

Motivation:

- Reduced H uptake
- To be analyzed
- Improved Safety
- Lowered toxicity

- Vertical EP Treatment at room temperature, **no cooling**
- 200 $\mu$ m Bulk EP done on pristine cavity RI02
- **Easy temperature control** vs standard mixture
- 0.1 $\mu$ m/min removal rate achieved
- **Oscillations** of the current depending on voltage
- **Uniform removal along the cavity**
- **Shiny aspect, no bubble trace observed:** Promising results
- Next: 800° C x 3h Heat treatment prior to flash VEP.
- The cavity will be tested at 2K at KEK: comparison with ILC recipe



## Proposal for FY2026

Test of RI02 cavity at 2K at KEK (no baking).

**Depending on the result, the next treatment may vary accordingly:**

- Baking with standard parameters (120°C-48h)
- Additional VEP
- Baking with '2-step' recipe (75°C-120°C)
- Additional horizontal recipe
- Mid-T baking
- ...

# **Continued Effort Towards Ultimate Performance for Accelerator Cavities**

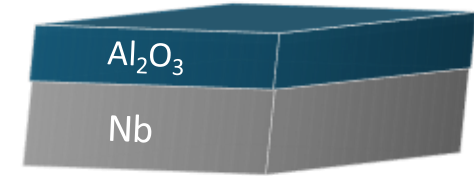
## **Activities in 2025 and Plan for 2026**

- |    |  |                                      |
|----|--|--------------------------------------|
| 1. | Theoretical Analysis                   | T. Kubo                              |
| 2. | Nb <sub>3</sub> Sn Thin Film Formation | R. Katayama                          |
| 3. | 3GHz cavity                            | Y. Fuwa                              |
| 4. | EP with organic solvent                | T. Goto                              |
| 5. | EP with depleted HF mixture            | F. Eozenou                           |
| 6. | <b>Atomic Layer Deposition</b>         | <b>Y. Kalboussi &amp; T. Proslie</b> |
| 7. | Faint Magnetic Shielding               | Y. Iwashita                          |

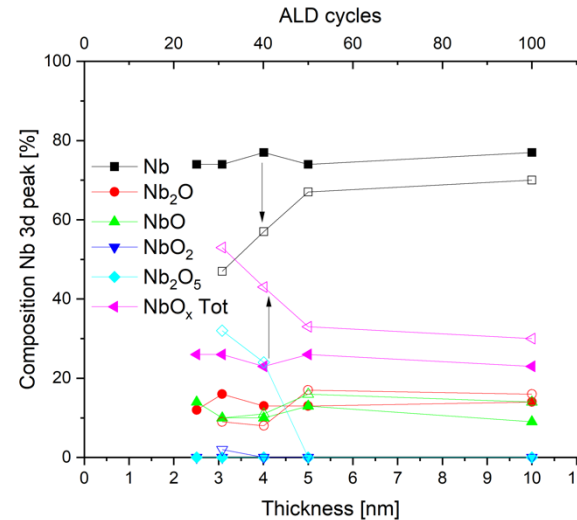
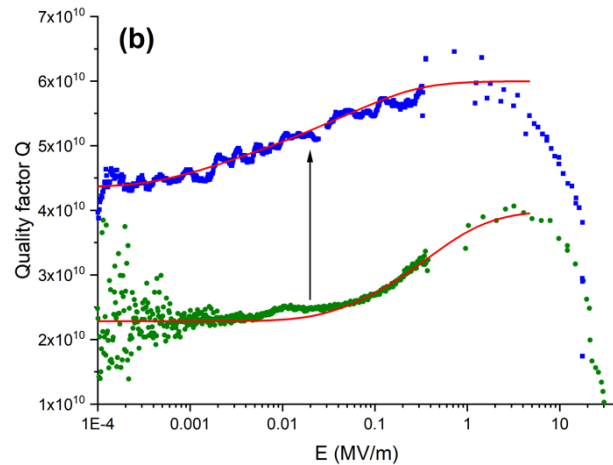
# ALD oxides and thermal treatments to mitigate Nb<sub>2</sub>O<sub>5</sub>

Y.kalboussi & T.Proslie

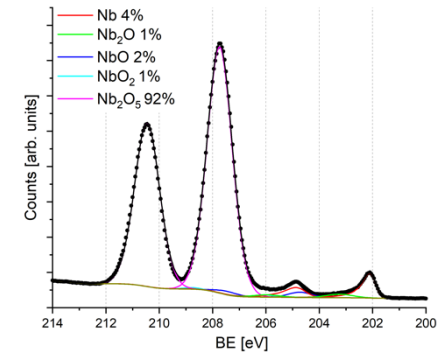
## Al<sub>2</sub>O<sub>3</sub> Thin films



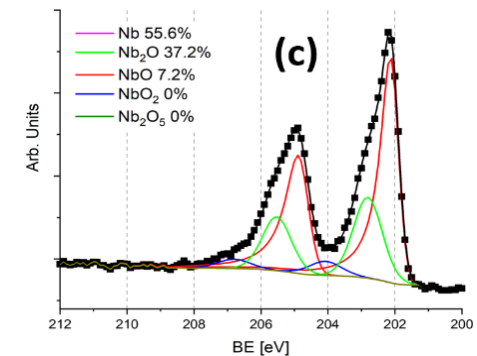
Al<sub>2</sub>O<sub>3</sub>-10nm- 650° C- 10hrs



Nb after EP + HPR



Nb after ALD + TT

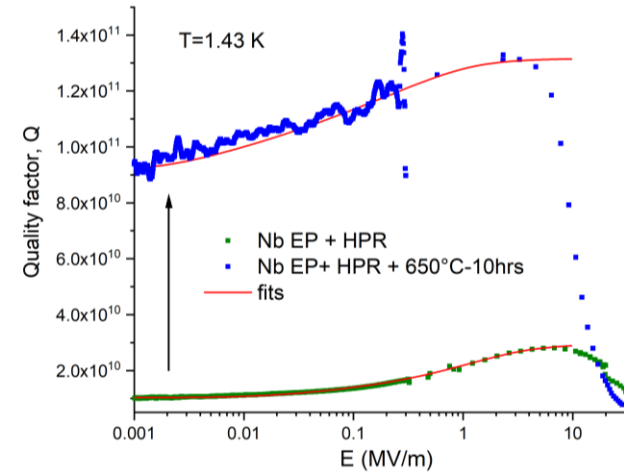
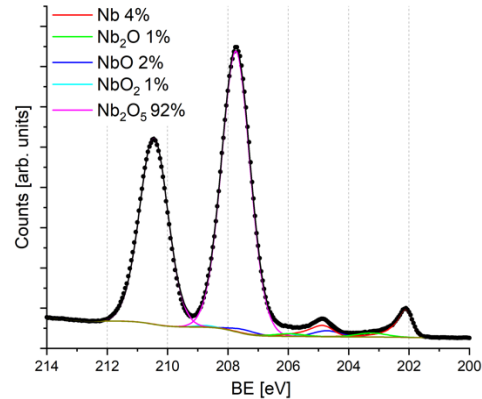
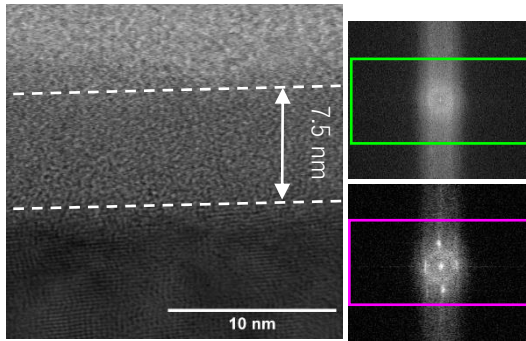


- The 10 nm Al<sub>2</sub>O<sub>3</sub> film + annealing at 650°C for few hours significantly improves the quality factors of the Nb cavity in the low field regime.
- Optimization of the Al<sub>2</sub>O<sub>3</sub> thickness -> Ok down to 2.5 nm.
- Other oxides such as ZrO<sub>2</sub> and Ta<sub>2</sub>O<sub>5</sub> are being studied.

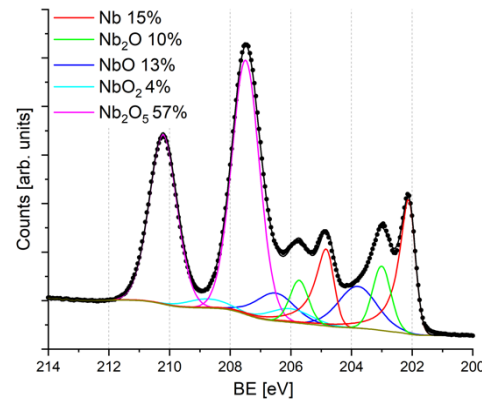
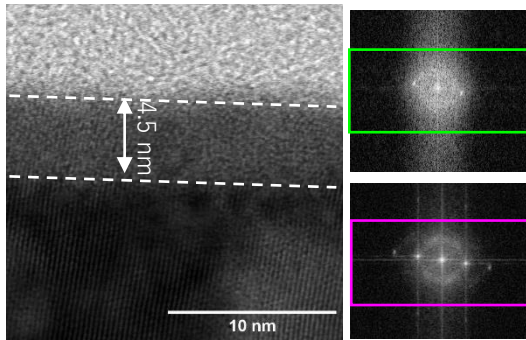
[1] Y. Kalboussi et al, "Reducing two-level system dissipations in 3D superconducting niobium resonators by atomic layer deposition and high-temperature heat treatment," *Applied Physics Letters*, 2024, 124 (13), pp. 134001. (10.1063/5.0202214). (hal-04470953). <https://doi.org/10.1063/5.0202214>

# Changing NbO<sub>x</sub> structure by thermal treatments

➤ Nb EP + HPR



➤ Nb EP + HPR + 650° C-10hrs + HPR



- World record Q values at low fields after air exposure and high pressure water rinsing (!)
- $\sigma_{\text{TLS}}$  and  $\tan(\delta_{\text{TLS}})$  decreased by a factor 10.
- Change in chemical / structure of the native NbO<sub>x</sub> with indication of NbO<sub>x</sub> (?) and Nb<sub>2</sub>O<sub>5</sub> crystals.
- Other thermal treatments are being investigated

✓ Proposal for FY2026:

RF test 1,3 Ghz cavities with new ALD coating/thermal treatments at KEK at high fields to correlate their performance with chemical and physical changes at the surface.

# Continued Effort Towards Ultimate Performance for Accelerator Cavities

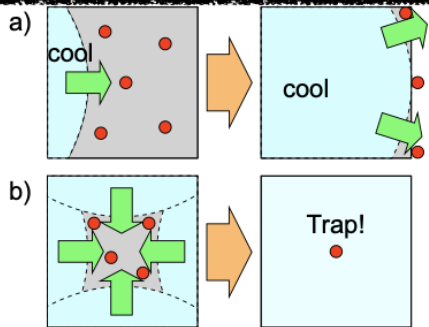
## Activities in 2025 and Plan for 2026

- |    |  |                           |
|----|--|---------------------------|
| 1. | Theoretical Analysis                   | T. Kubo                   |
| 2. | Nb <sub>3</sub> Sn Thin Film Formation | R. Katayama               |
| 3. | 3GHz cavity                            | Y. Fuwa                   |
| 4. | EP with organic solvent                | T. Goto                   |
| 5. | EP with depleted HF mixture            | F. Eozenou                |
| 6. | Atomic Layer Deposition                | Y. Kalboussi & T. Proslie |
| 7. | Faint Magnetic Shielding               | Y. Iwashita               |

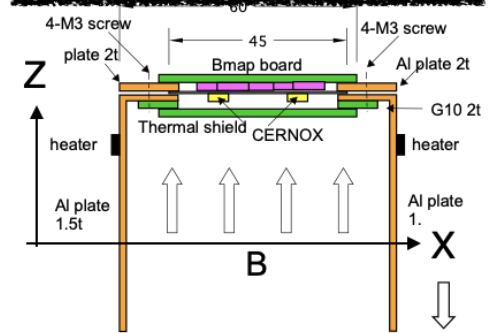
# Faint Magnetic Shield by Meissner Effect

## — Preview of Result —

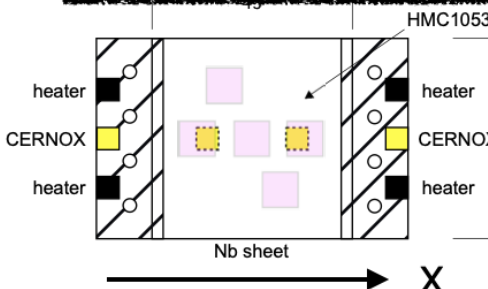
Flux may be trapped in Nb.



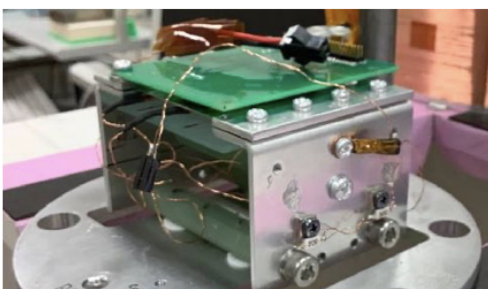
Side view of sensor layout



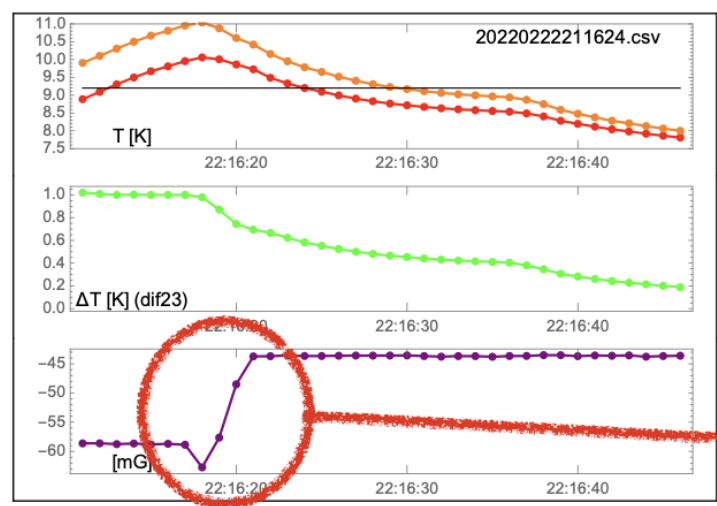
Top view of sensor layout



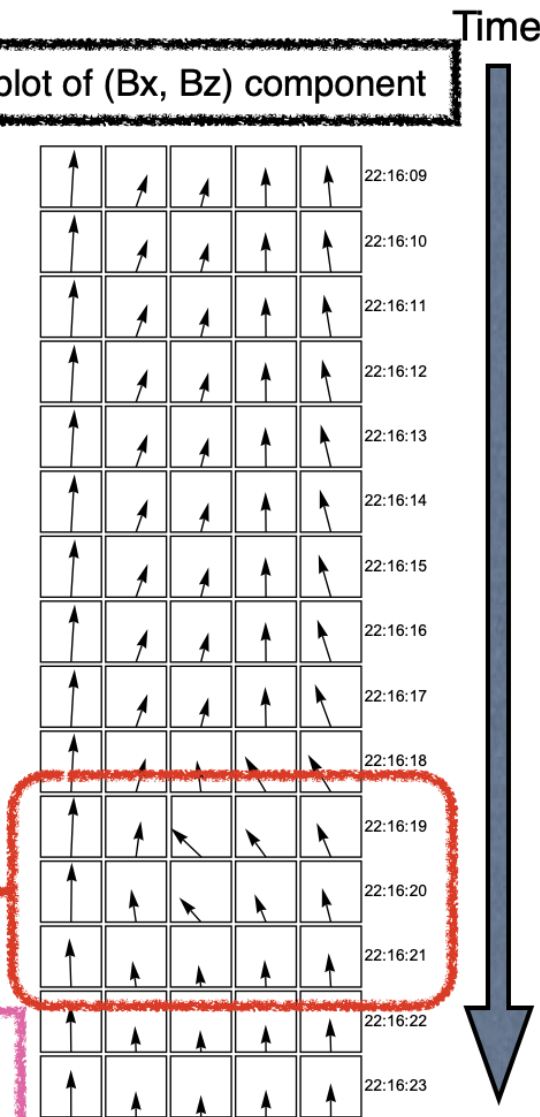
Experimental setup



Temperature change and flux jump



Vector plot of (Bx, Bz) component



2026: Next plan is to realize RRR measurement on the same setup.

# Summary

## Achievement in 2025

- **Theoretical Understanding:**  
Established microscopic theory for nonlinear electromagnetic response using Keldysh-Usadel framework.
- **Nb<sub>3</sub>Sn Sputtering:**  
Completed simulations for Nb:Sn (3:1) flux distribution and successfully tested SUS-Al mixed cathode prototypes.
- **Vertical Test of 3 GHz cavity:**  
Achieved  $E_{\text{acc}} \sim 22$  MV/m and  $Q_0 \sim 2 \times 10^9$  for a bare 3GHz cavity at 2K.
- **Surface Treatment:**  
Developed organic solvent EP and depleted HF mixture EP.
- **ALD:**  
Investigated thermal treatments for ALD-coated surface.
- **Fain Magnetic Shielding:**  
Performed preliminary experiment for shielding with the Meissner effect of Nb.

R&D effort is continued towards ultimate cavity performance.